

## Low Noise Amplifier with Bypass Switch for LTE Low Band

### FEATURES

- Operating frequency 703MHz to 960MHz
- Noise figure(NF) =0.6dB
- High power gain =13.5dB
- Insertion Loss in bypass mode =3dB
- Gain mode IIP3ib=+7dBm
- Gain mode input 1dB-compression point=-1.0dBm
- Bypass mode input 1dB-compression point=+5.0dBm
- Supply voltage: 1.5V to 3.3V
- Gain mode current 9mA
- Bypass mode current <1uA
- Input and output DC decoupled
- Requires only one input matching inductor
- Integrated matching for the output
- FCDFN 1.1mmX0.7mmX0.37mm -6L package
- 2kV HBM ESD protection (including RFIN and RFOUT pin)

### GENERAL DESCRIPTION

- The AW15208LFDR is a Low Noise Amplifier with bypass designed for LTE receiver applications. The AW15208LFDR requires only one external input matching inductor, reduces assembly complexity and the PCB area, enabling a cost-effective solution.
- The AW15208LFDR achieves low noise figure, high linearity, high gain, over a wide range of supply voltages from 1.5V up to 3.3V. All these features make AW15208LFDR an excellent choice for LTE LNA as it improves sensitivity with low noise figure and high gain, provides better immunity against jammer signals with high linearity, reduces filtering requirement of preceding stage and hence reduces the overall cost.
- The AW15208LFDR is available in a small lead-free, RoHS-Compliant, FCDFN 1.1mmX0.7mmX0.37 mm -6L package.

### APPLICATIONS

- Cell phones
- Tablets
- Other RF front-end modules

### TYPICAL APPLICATION CIRCUIT

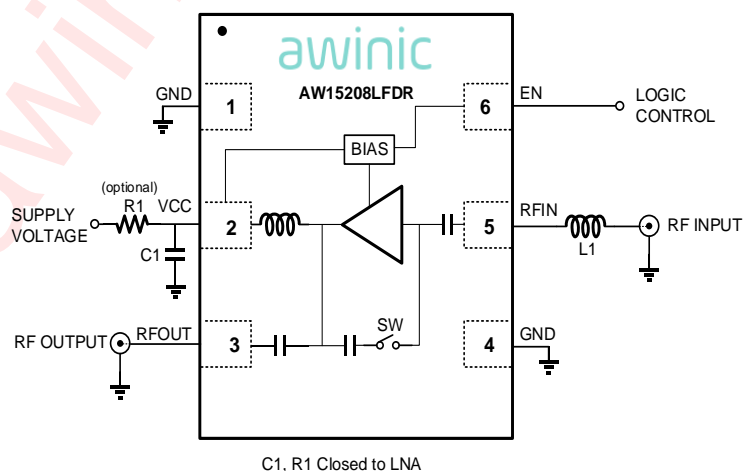


Figure 1 Typical Application Circuit of AW15208LFDR

## PIN CONFIGURATION AND TOP MARK

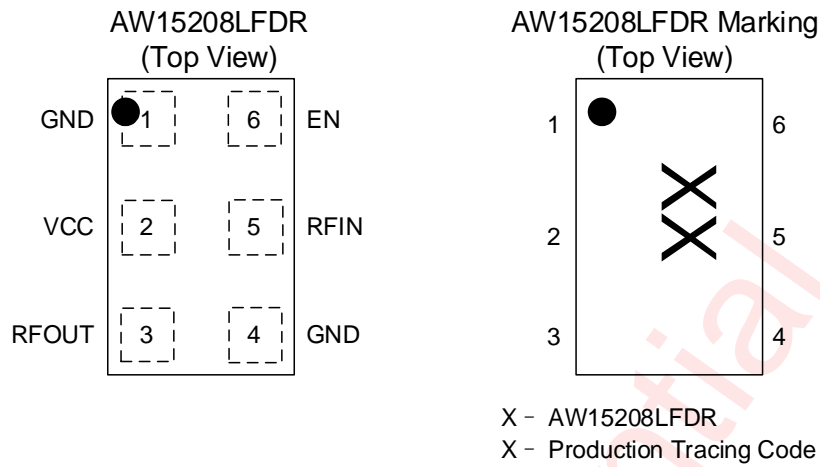


Figure 2 Pin Configuration and Top Mark

## PIN DEFINITION

No.	NAME	DESCRIPTION
1	GND	Ground
2	VCC	Supply connection
3	RFOUT	RF output
4	GND	Ground
5	RFIN	RF input
6	EN	EN (high level) supports 1.8V/2.8V IO with internal 150kohm pull-down resistor

## FUNCTIONAL BLOCK DIAGRAM

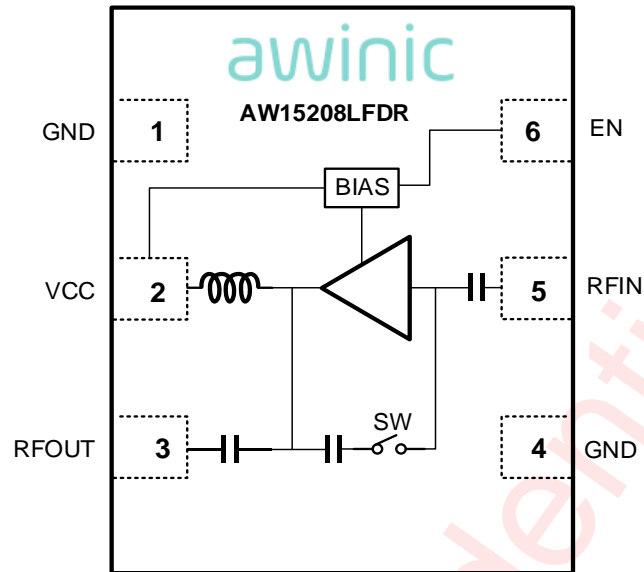


Figure 3 Functional Block Diagram

## ORDERING INFORMATION

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW15208LFDR	-40°C~85°C	FCDFN 1.1mmX 0.7mm -6L	X	MSL1	ROHS+HF	3000 units/Tape & Reel

**ABSOLUTE MAXIMUM RATINGS**<sup>[1]</sup>

PARAMETERS	RANGE
Supply voltage VCC	-0.3V to 3.6V
EN pin voltage	-0.3V to 3.6V
Supply maximum current ICC	30mA
RF input power Pin	25dBm
Maximum Junction temperature T <sub>JMAX</sub>	150°C
Storage temperature T <sub>STG</sub>	-65°C to 150°C
Operating free-air temperature range	-40°C to 85°C
Lead temperature (Soldering 10 Seconds)	260°C
Maximum leakage current (under Maximum Voltage)	1uA
Maximum EN control current	1uA
ESD <sup>[2]</sup>	
HBM	±2kV
CDM	±1kV
Latch-up	
Standard: JEDEC EIA/JESD78E	+IT: +200mA -IT: -200mA

[1] Conditions out of those ranges listed in “absolute maximum ratings” may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in “recommended operating conditions”. Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

[2] The human body model is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. Test method: ANSI/ESDA/JEDEC JS-001-2017. The CDM test method: ANSI/ESDA/JEDEC JS-002-2018.

**ELECTRICAL CHARACTERISTICS**

TA=+25°C, V<sub>CC</sub>=2.8V, EN=1.8V/2.8V, frequency=703MHz to 960MHz. Input matched to 50Ω using a 15nH<sup>[3]</sup> inductor in series. (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
<b>DC Electrical Characteristic</b>						
VCC	Supply Voltage		1.5		3.3	V
VEN	Digital Input-Logic High		0.8		3.3	V
	Digital Input-Logic Low				0.45	V
<b>Gain Mode</b>						
ICC	Supply Current			9.0	12.5	mA
Gp	Power Gain	703MHz-850MHz [4]	11.5	13.0	14.5	dB
		850MHz-960MHz [4]	11.5	13.5	14.5	
RLin	Input Return Loss	703MHz-850MHz [4]	6.0	10.0		dB
		850MHz-960MHz [4]	6.0	10.0		
RLout	Output Return Loss	703MHz-850MHz [4]	6.0	10.0		dB
		850MHz-960MHz [4]	6.0	10.0		
ISL	Reverse Isolation	703MHz-850MHz [4]	17.0	21.0		dB
		850MHz-960MHz [4]	17.0	21.0		
NF	Noise Figure	703MHz-850MHz [4][5]		0.6	1.1	dB
		850MHz-960MHz [4][5]		0.66	1.1	
IP1dB	In-band input 1dB-compression point	703MHz-850MHz [4]	-6.0	-1.0		dBm
		850MHz-960MHz [4]	-6.0	-2.0		
IIP3ib	In-band input 3 <sup>rd</sup> -order intercept point	703MHz-850MHz [4]	0	8.0		dBm
		850MHz-960MHz [4]	0	7.0		
ton	turn-on time	time from V <sub>EN</sub> ON to 90% of the gain		2	4	μs
toff	turn-off time	time from V <sub>EN</sub> OFF to 10% of the gain		1	2	μs
K	Stability factor	0.2MHz-10GHz	1			
<b>Bypass Mode</b>						
ICC	Supply Current	VEN<0.45V			1	uA
Gp	Power Gain	703MHz-850MHz [4]	-4.5	-3.0		dB
		850MHz-960MHz [4]	-4.5	-3.0		
RLin	Input Return Loss	703MHz-850MHz [4]	5.0	10.0		dB
		850MHz-960MHz [4]	5.0	8.0		
RLout	Output Return Loss	703MHz-850MHz [4]	5.0	10.0		dB
		850MHz-960MHz [4]	5.0	8.0		
IP1dB	In-band input 1dB-compression point	703MHz-850MHz [4]	1.0	5.0		dBm
		850MHz-960MHz [4]	1.0	4.0		
IIP3ib	In-band input 3 <sup>rd</sup> -order intercept point	703MHz-850MHz [4]	9.0	12.0		dBm
		850MHz-960MHz [4]	9.0	12.0		

[3] High quality-factor 15nH inductor.

[4] Input power is -25dBm.

[5] PCB losses are subtracted.

TA=+25°C , V<sub>CC</sub>=1.8V, EN=1.8V, frequency=703MHz to 960MHz. Input matched to 50Ω using a 15nH<sup>[3]</sup> inductor in series. (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
<b>DC Electrical Characteristic</b>						
VCC	Supply Voltage		1.5		3.3	V
VEN	Digital Input-Logic High		0.8		3.3	V
	Digital Input-Logic Low				0.45	V
<b>Gain Mode</b>						
ICC	Supply Current			7.6	11	mA
Gp	Power Gain	703MHz-850MHz [4]	11.5	12.8	14.5	dB
		850MHz-960MHz [4]	11.5	13.3	14.5	
RLin	Input Return Loss	703MHz-850MHz [4]	6.0	10.0		dB
		850MHz-960MHz [4]	6.0	10.0		
RLout	Output Return Loss	703MHz-850MHz [4]	6.0	10.0		dB
		850MHz-960MHz [4]	6.0	10.0		
ISL	Reverse Isolation	703MHz-850MHz [4]	17.0	21.0		dB
		850MHz-960MHz [4]	17.0	21.0		
NF	Noise Figure	703MHz-850MHz [4][5]		0.63	1.1	dB
		850MHz-960MHz [4][5]		0.70	1.1	
IP1dB	In-band input 1dB-compression point	703MHz-850MHz [4]	-7.0	-5.6		dBm
		850MHz-960MHz [4]	-7.5	-6.3		
IIP3ib	In-band input 3rd-order intercept point	703MHz-850MHz [4]	0	6.0		dBm
		850MHz-960MHz [4]	0	5.0		
ton	turn-on time	time from V <sub>EN</sub> ON to 90% of the gain		2	4	μs
toff	turn-off time	time from V <sub>EN</sub> OFF to 10% of the gain		1	2	μs
K	Stability factor	0.2MHz-10GHz	1			
<b>Bypass Mode</b>						
ICC	Supply Current	VEN<0.45V			1	uA
Gp	Power Gain	703MHz-850MHz [4]	-4.5	-3.3		dB
		850MHz-960MHz [4]	-4.5	-3.3		
RLin	Input Return Loss	703MHz-850MHz [4]	5.0	10.0		dB
		850MHz-960MHz [4]	5.0	8.0		
RLout	Output Return Loss	703MHz-850MHz [4]	5.0	10.0		dB
		850MHz-960MHz [4]	5.0	8.0		
IP1dB	In-band input 1dB-compression point	703MHz-850MHz [4]	1.0	5.0		dBm
		850MHz-960MHz [4]	1.0	4.0		

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
IIP3ib	In-band input	703MHz-850MHz [4]	9.0	12.0		dBm
	3 <sup>rd</sup> -order intercept point	850MHz-960MHz [4]	9.0	12.0		

[3] High quality-factor 15nH inductor.

[4] Input power is -25dBm.

[5] PCB losses are subtracted.

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## APPLICATION INFORMATION

### Choice of components

- The AW15208LFDR requires only one external inductor for input matching. If the device/phone manufacturers implement very good power supply filtering on their boards, the bypass capacitor mentioned in this application circuit may be optional. With the power supply decoupling capacitor, better performance would be received, like a little higher gain, etc. The value is optimized for the key performance, such as higher power gain, lower noise figure, and better return loss. Typical value of inductor is 20nH with high quality factor, and capacitor is 1nF. The typical application circuit can refer to Figure1.
- The output of AW15208LFDR is internally matched to 50 ohm and a DC blocking capacitor is integrated on-chip, thus no external component is required at the output.
- The AW15208LFDR should be placed close to the diversity antenna with the input-matching inductor. Use 50 ohm micro-strip lines to connect RF INPUT and RF OUTPUT. Bypass capacitor need be located close to the device. For long V<sub>CC</sub> lines, it may be necessary to add more decoupling capacitors. Proper grounding of the GND pins is very important.

Following tables show recommended inductor and capacitor values.

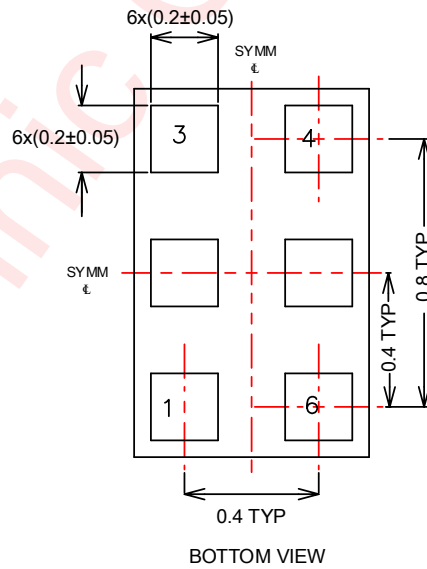
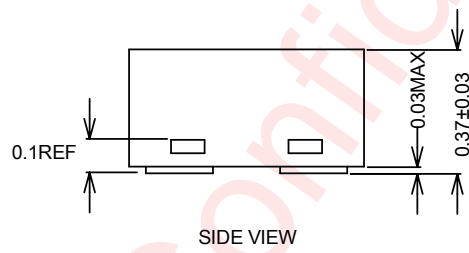
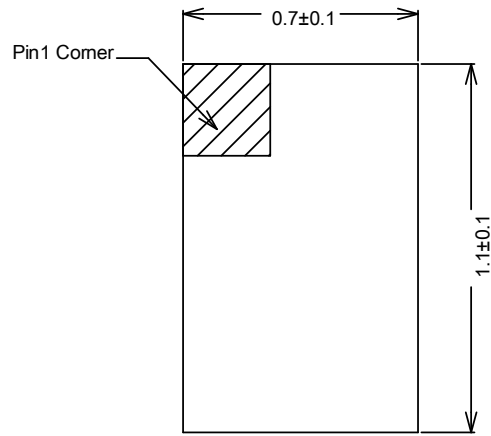
**Inductor Selection Table**

Component	Part	Typical(nH)	Q(min)	Frequency(MHz)	MFR	Size
L1	LQW15A	15	25	250	Murata	0402

**Capacitor Selection Table**

Component	Part	Typical(pF)	Voltage(V)	MFR	Size
C1	GRM155	1000	50	Murata	0402

## PACKAGE DESCRIPTION



Unit : mm

Figure 4 Package Outline

## LAND PATTERN

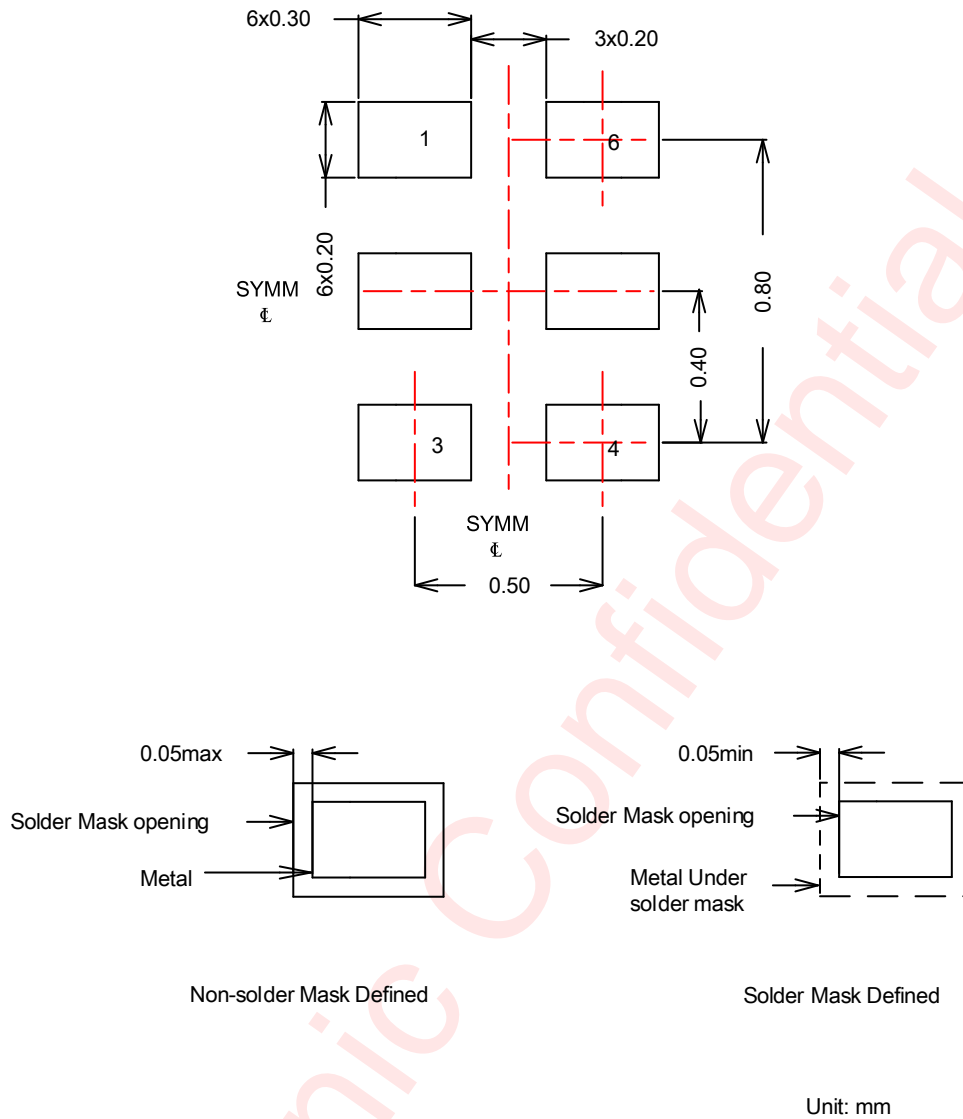
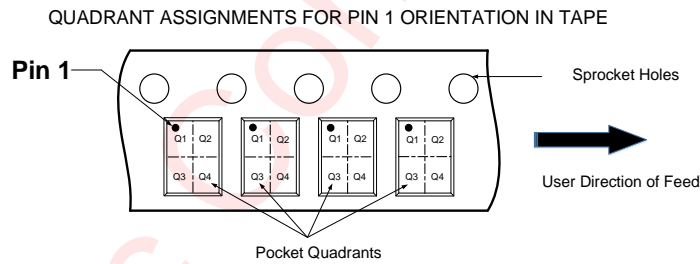
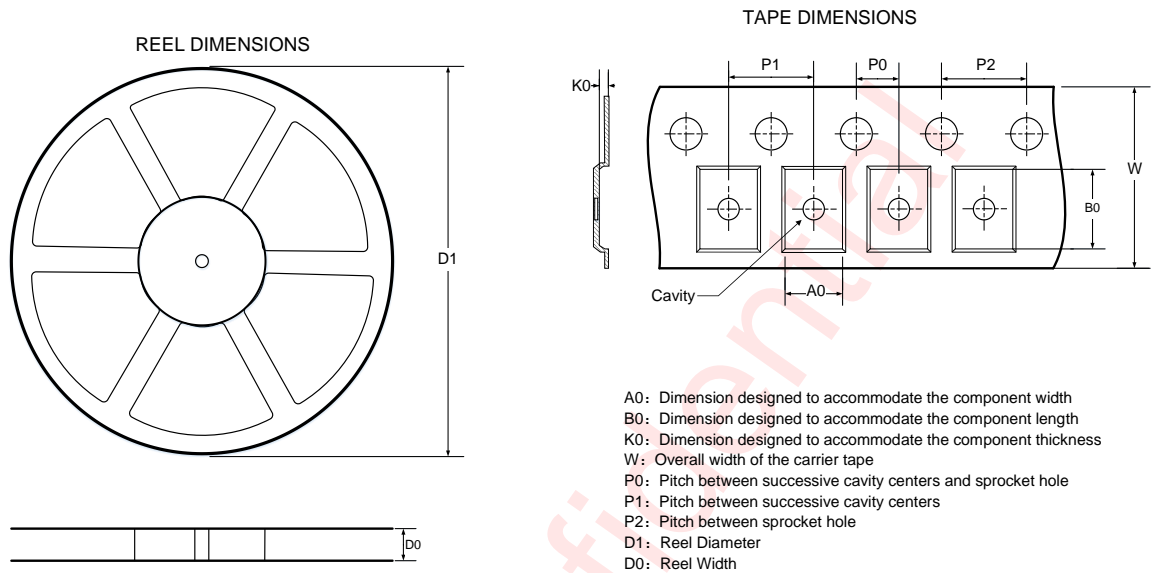


Figure 5 Land Pattern

TAPE & REEL DESCRIPTION



DIMENSIONS AND PIN1 ORIENTATION

D1 (mm)	D0 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
178	8.4	0.8	1.2	0.55	2	2	4	8	Q1

All dimensions are nominal

Figure 6 Tape & Reel Description

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**REVISION HISTORY**

Version	Date	Change Record
V1.0	Mar. 2019	Officially Released
V1.1	Dec. 2019	Update Electrical Characteristics
V1.2	Feb. 2020	Add maximal leakage current and EN control current
V1.3	Mar. 2020	Update Electrical Characteristics
V1.4	Nov. 2020	Update Electrical Characteristics

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